NSN 5961-01-171-7671

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-171-7671

Inclosure Material:

Plastic

Overall Length:

0.620 inches

Overall Height:

0.190 inches

Overall Width:

0.395 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

300.0 collector to emitter voltage/static/base open and 600.0 collector-to-emitter, with voltage between base and emitter and 9.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 8.00 amperes source cutoff current and 4.00 amperes source cutoff current and 12.00 amperes source cutoff current blank

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

40.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0